

International
IOR Rectifier

50WQ03FN

SCHOTTKY RECTIFIER

5.5 Amp

$$I_{F(AV)} = 5.5\text{Amp}$$

$$V_R = 30\text{V}$$

Major Ratings and Characteristics

Characteristics	Values	Units
$I_{F(AV)}$ Rectangular waveform	5.5	A
V_{RRM}	30	V
I_{FSM} @ $t_p = 5\mu\text{s}$ sine	320	A
V_F @ 5A , $T_J = 125^\circ\text{C}$	0.35	V
T_J range	-40 to 150	$^\circ\text{C}$

Description/ Features

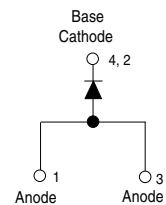
The 50WQ03FN surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

Case Styles



D-PAK (TO-252AA)



Voltage Ratings

Part number	50WQ03FN
V_R Max. DC Reverse Voltage (V)	30
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	50WQ...	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 5	5.5	A	50% duty cycle @ $T_C = 136^\circ\text{C}$, rectangular wave form
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	320	A	5 μs Sine or 3 μs Rect. pulse
	130		10ms Sine or 6ms Rect. pulse
E_{AS} Non-Repetitive Avalanche Energy	10	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 2.0$ Amps, $L = 5$ mH
I_{AR} Repetitive Avalanche Current	2.0	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	50WQ...	Units	Conditions
V_{FM} Max. Forward Voltage Drop * See Fig. 1 (1)	0.46	V	@ 5A $T_J = 25^\circ\text{C}$
	0.53	V	@ 10A
	0.35	V	@ 5A $T_J = 125^\circ\text{C}$
	0.46	V	@ 10A
I_{RM} Max. Reverse Leakage Current * See Fig. 2 (1)	3	mA	$T_J = 25^\circ\text{C}$
	58	mA	$T_J = 125^\circ\text{C}$
$V_{F(TO)}$ Threshold Voltage	0.19	V	$T_J = T_J$ max.
r_t Forward Slope Resistance	22.22	m Ω	
C_T Typical Junction Capacitance	590	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) 25°C
L_S Typical Series Inductance	5.0	nH	Measured lead to lead 5mm from package body

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	50W...	Units	Conditions
T_J Max. Junction Temperature Range (*)	-40 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-40 to 150	$^\circ\text{C}$	
R_{thJC} Max. Thermal Resistance Junction to Case	3.0	$^\circ\text{C/W}$	DC operation * See Fig. 4
wt Approximate Weight	0.3 (0.01)	g (oz.)	
Case Style	D - PAK		Similar to TO-252AA
Marking Device	50WQ03FN		

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

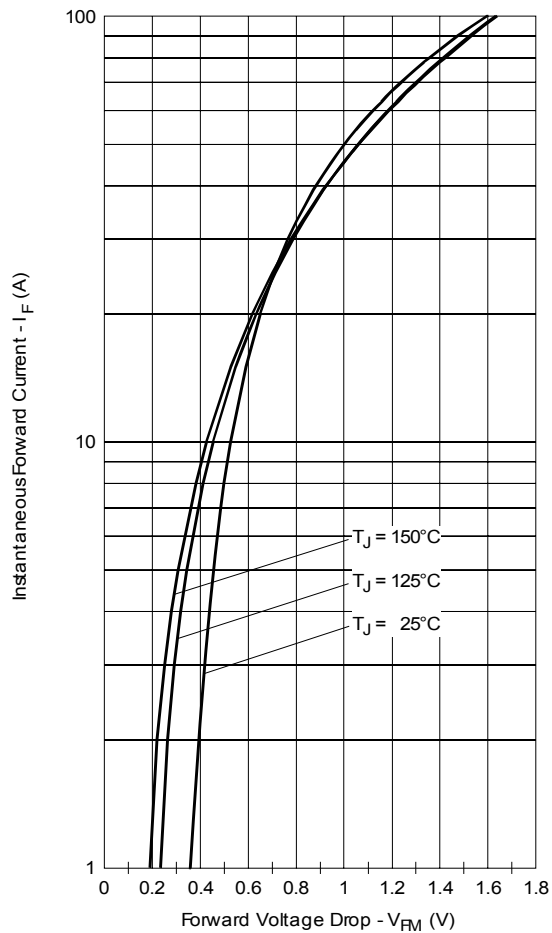


Fig. 1 - Maximum Forward Voltage Drop Characteristics

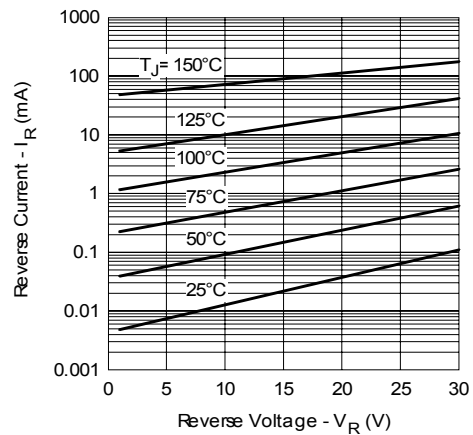


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

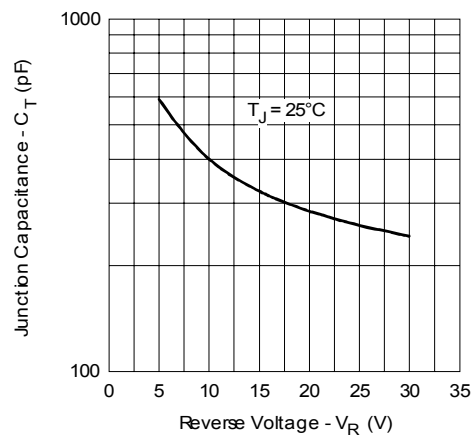


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

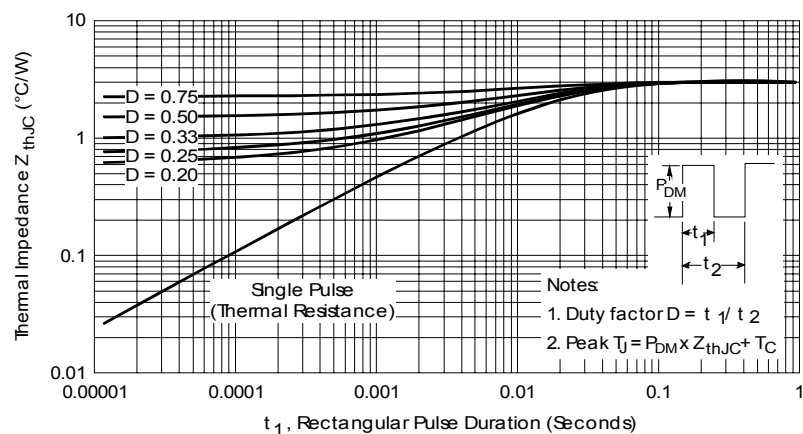


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

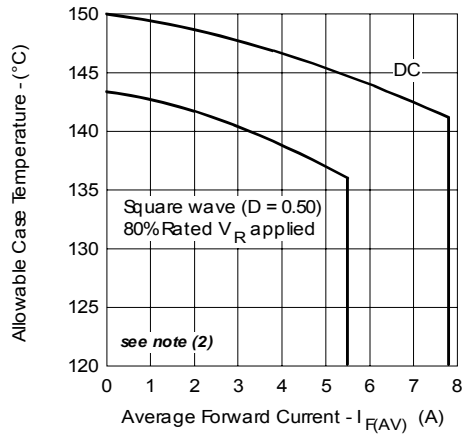


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

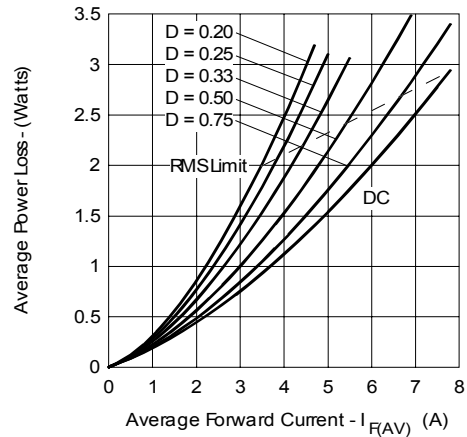


Fig. 6 - Forward Power Loss Characteristics

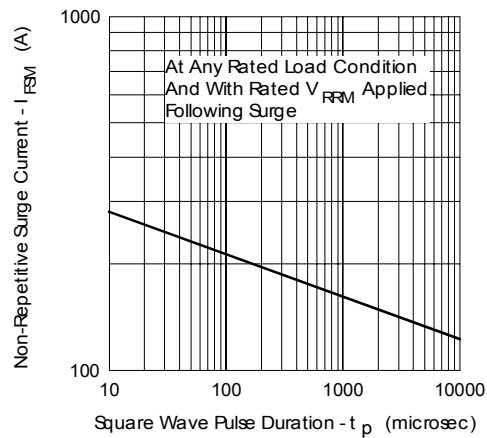


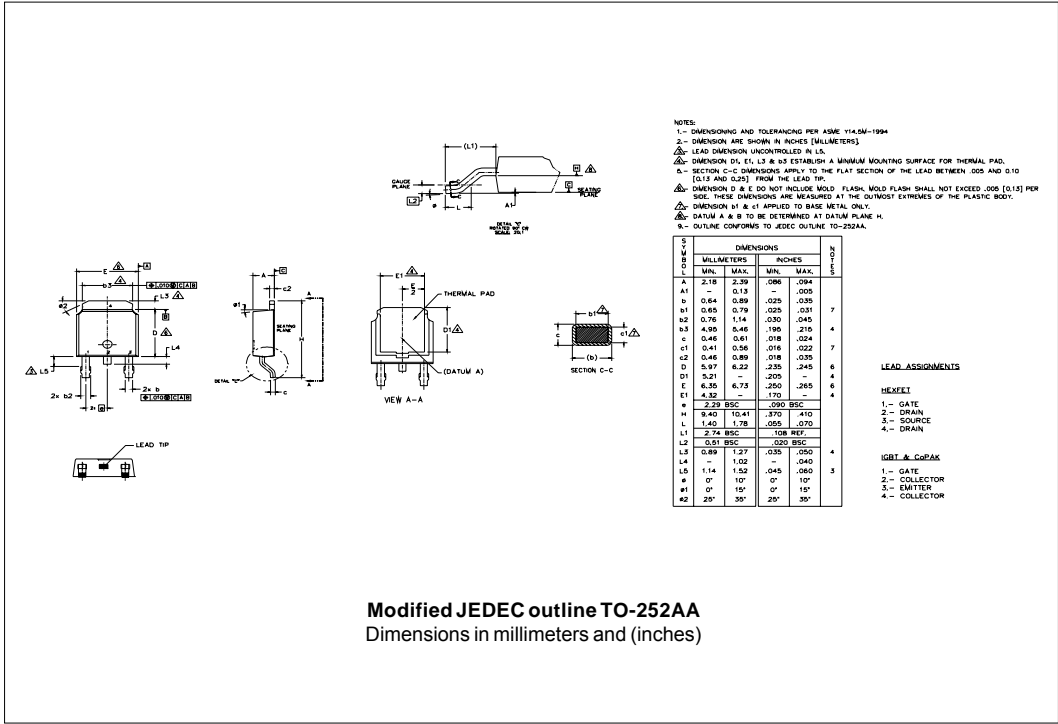
Fig. 7 - Maximum Non-Repetitive Surge Current

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

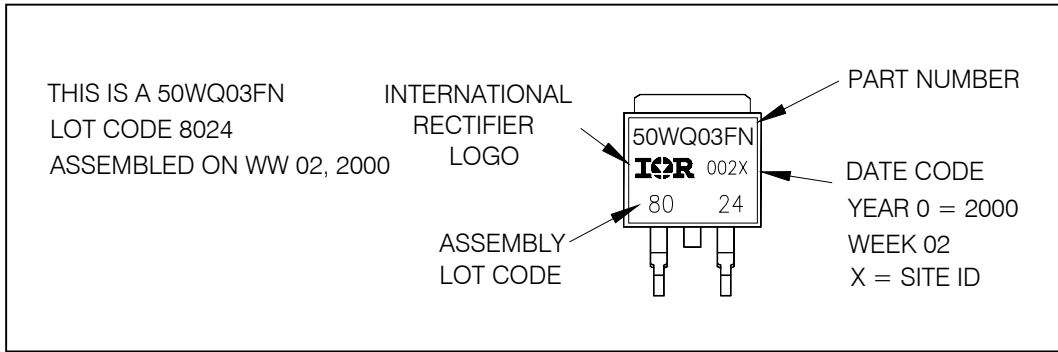
Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\%$ rated V_R

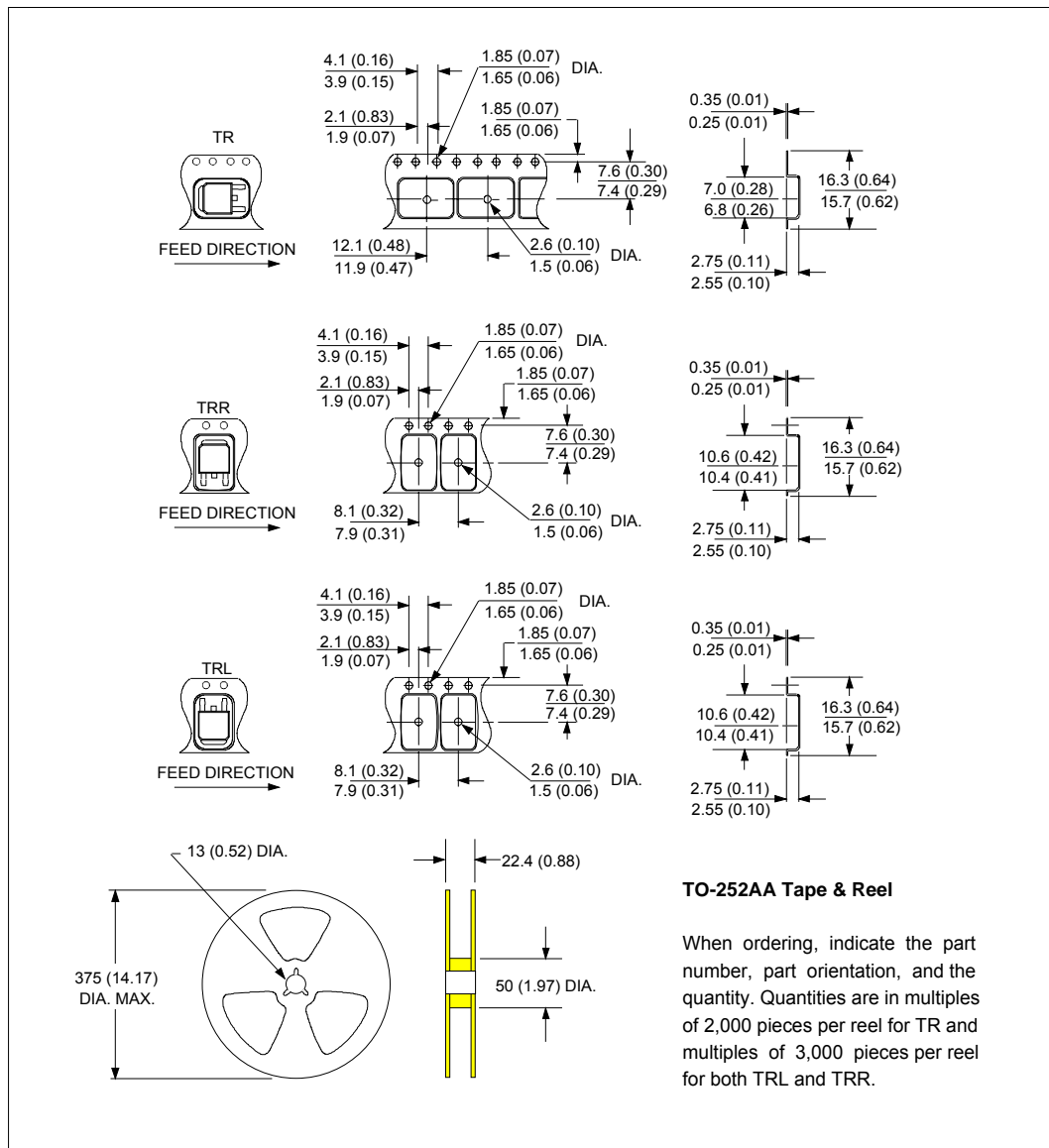
Outline Table



Part Marking Information



Tape & Reel Information



Ordering Information Table

Device Code						
	50	W	Q	03	FN	TRL -
	1	2	3	4	5	6 7
1	-	Current Rating (5.5A)				
2	-	Package Identifier				
		W = D-Pak				
3	-	Schottky "Q" Series				
4	-	Voltage Rating (03 = 30V)				
5	-	FN = TO-252AA				
6	-	<ul style="list-style-type: none"> • none = Tube (50 pieces) • TR = Tape & Reel • TRL = Tape & Reel (Left Oriented) • TRR = Tape & Reel (Right Oriented) 				
7	-	<ul style="list-style-type: none"> • none = Standard Production • PbF = Lead-Free 				

Data and specifications subject to change without notice.
 This product has been designed and qualified for AEC Q101 Level.
 Qualification Standards can be found on IR's Web site.



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